

# Solid-State Lighting Science

## Energy Frontier Research Center

Science for our Energy Future  
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Nation's



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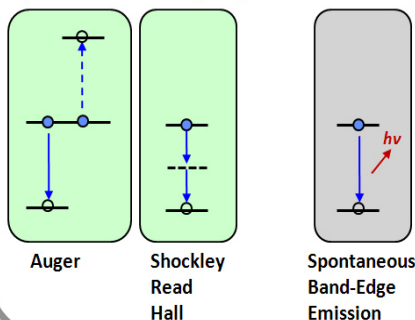
### Research Topics

- Point Defects in InGaN: Microscopic Origin and Influence on Macroscopic Luminescence
- Competing Energy Conversion Routes in Light-Emitting InGaN
- Lasers for Solid-State Lighting
- Strongly Coupled Exciton-Photon Systems
- Dipole-dipole Energy Transfer between Nanostructures
- Surface Plasmonic Intermediaries to Exciton-Photon Interactions
- Nanowires: Synthesis and Properties of Radial Heterostructures
- Crystal Morphology Evolution during Patterned Growth and Coalescence
- Nanodots: Nonlinear Luminescence Dynamics
- Novel Eu+++ Materials for Wavelength Downconversion

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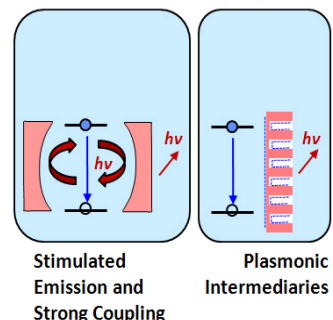
### 1 Competing Radiative and Non-Radiative Processes

Develop a microscopic understanding of the competition between radiative and non-radiative e-h recombination: spontaneous emission from planar structures.



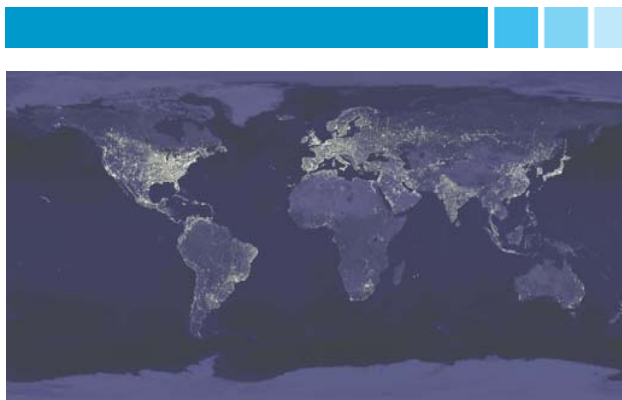
### 2 Beyond Free-Space Spontaneous Emission

Explore energy conversion routes that short-circuit conventional spontaneous emission but end in free-space photons.



### 3 Beyond-2D

Explore the use of non-planar nanoscale structures to modify energy conversion routes so that they may be (a) isolated and better understood, and (b) engineered and optimized.



### Why is SSL Important?

Lighting uses ~20% of U.S. electricity, ~\$50B/year. Solid-state lighting (SSL) could reduce that energy use by 3–6 times. SSL devices use semiconductors (crystalline, organic, or polymer light-emitting diodes) to produce light rather than filaments / plasma / gas. Compared to incandescent lights, SSL creates visible light with greatly reduced heat generation / parasitic energy loss, much greater shock / vibration resistance, with lifetimes of 15 years or more. SSL is replacing incandescents in many applications requiring durability, compactness, cool operation and/or directionality. However, currently SSL is still ~4-6 times away from achieving its full potential.

### Mission

We seek to improve the energy-efficiency of the way we light our homes and offices, which currently accounts for 20% of the nation's electrical energy use. Solid-State Lighting (SSL) has the potential to cut that energy consumption in half – or even more.

### The SSLS EFRC seeks to:

- 1) Deepen the foundational science underlying SSL technology while informing and being informed by SSL technology
- 2) Create an environment that brings together a critical mass of world-class scientists & resources to enable synergistic collaboration that is more than the sum of its parts.
- 3) Share knowledge actively with specialists (scientists, technologists) and non-specialists (students, public, and government).

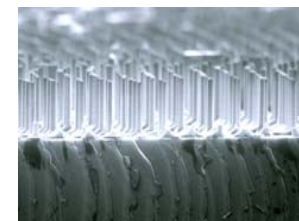
InGaN-based growth: Metalorganic chemical vapor deposition (MOCVD) is used for the growth of the custom InGaN-based multiple quantum well and LED structures studied in the Solid-State Lighting Science EFRC.



Evaluating Efficiency: Emission from a green light-emitting diode (LED) test structure fabricated at Sandia National Laboratories. Understanding efficiency limitations of InGaN LEDs is a major thrust of our EFRC.



Photoluminescence (PL) lifetime measurement: Researchers measure the PL lifetime of a quantum dot solution. We are developing these materials as red-emitters for SSL, in an effort to produce highly efficient light sources with good color rendering.



Nanowire-based LEDs: SEM of an ordered gallium nitride (GaN) nanowire array fabricated on sapphire wafers by a two-step etching process. GaN-based nanowires may be used to create higher performance LEDs in the future due to their unique properties.